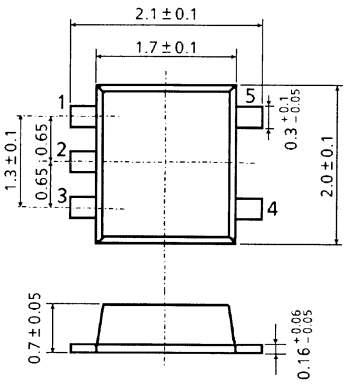
Silicon N Channel MOS Type (U-MOSⅢ)/Silicon Epitaxial Schottky Barrier Diode

SSM5H16TU

DC-DC Converter Applications

- 1.8-V drive
- Combined an N-ch MOSFET and a Schottky barrier diode in one package.
- Low $R_{DS\ (ON)}$ and Low V_F

Unit: mm



1 : GATE 4 : CATHODE
2 : SOURCE 5 : DRAIN
3 : ANODE

UFV

JEDEC	—
JEITA	—
TOSHIBA	2-2R1A

Weight: 7 mg (typ.)

Absolute Maximum Ratings

MOSFET (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	30	V
Gate-source voltage		V_{GSS}	± 12	V
Drain current	DC	I_D	1.9	A
	Pulse	I_{DP}	3.8	
Drain power dissipation		P_D (Note 1)	0.5	W
		t = 10s	0.8	
Channel temperature		T_{ch}	150	°C

Schottky Barrier Diode (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Reverse voltage	V_R	30	V
Average forward current	I_O	0.8	A
Peak one cycle surge forward current	I_{FSM}	6 (50Hz)	A
Junction temperature	T_j	125	°C

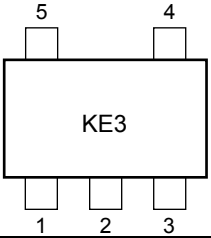
MOSFET and Diode (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Storage temperature range	T_{stg}	−55 to 125	°C

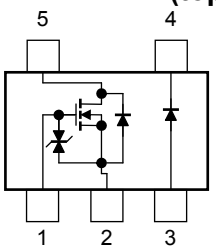
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board
(25.4 mm × 25.4 mm × 1.6 mm, Cu pad: 645 mm^2)

Marking



Equivalent Circuit (top view)



MOSFET

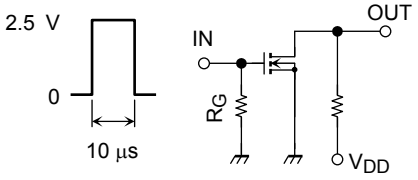
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-Source breakdown voltage		$V_{(BR)\ DSS}$	I_D = 1 mA, V_{GS} = 0 V	30	—	—	V
		$V_{(BR)\ DSX}$	I_D = 1 mA, V_{GS} = −12 V	18	—	—	
Drain cut-off current		I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V	—	—	1	μA
Gate leakage current		I_{GSS}	V_{GS} = ± 12 V, V_{DS} = 0 V	—	—	±1	μA
Gate threshold voltage		V_{th}	V_{DS} = 3 V, I_D = 1 mA	0.4	—	1.0	V
Forward transfer admittance		$\|Y_{fs}\|$	V_{DS} = 3 V, I_D = 1.0 A (Note 2)	2.0	3.9	—	S
Drain–source ON-resistance		$R_{DS\ (ON)}$	I_D = 1.0 A, V_{GS} = 4.0 V (Note 2)	—	103	133	mΩ
			I_D = 0.8 A, V_{GS} = 2.5 V (Note 2)	—	125	177	
			I_D = 0.5 A, V_{GS} = 1.8 V (Note 2)	—	165	296	
Input capacitance		C_{iss}	V_{DS} = 15V, V_{GS} = 0 V, f = 1 MHz	—	123	—	pF
Output capacitance		C_{oss}		—	43	—	
Reverse transfer capacitance		C_{rss}		—	18	—	
Total gate charge		Q_g	V_{DS} = 15V, I_D = 1.9 A V_{GS} = 4 V	—	1.9	—	nC
Gate-source charge		Q_{gs}		—	1.1	—	
Gate-drain charge		Q_{gd}		—	0.8	—	
Switching time	Turn-on time	t_{on}	V_{DD} = 15 V, I_D = 1.0 A, V_{GS} = 0 to 2.5 V, R_G = 4.7 Ω	—	9.2	—	ns
	Turn-off time	t_{off}		—	6.4	—	
Drain-source forward voltage		V_{DSF}	I_D = -1.9 A, V_{GS} = 0 V (Note 2)	—	-0.83	-1.2	V

Note 2: Pulse test

Switching Time Test Circuit

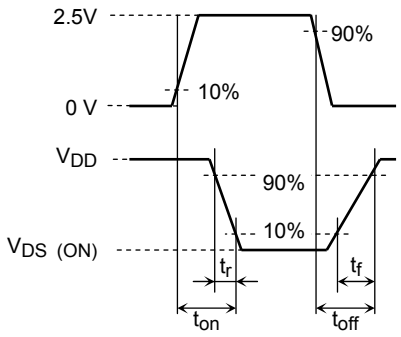
(a) Test Circuit



V_{DD} = 15 V
R_G = 4.7 Ω
Duty≤ 1%
V_{IN}: t_r, t_f < 5 ns
Common Source
Ta = 25°C

(b) V_{IN}

(c) V_{OUT}



Precaution

V_{th} can be expressed as voltage between gate and source when the low operating current value is I_D = 1 mA for this product. For normal switching operation, $V_{GS\ (on)}$ requires a higher voltage than V_{th} and $V_{GS\ (off)}$ requires a lower voltage than V_{th}.

(The relationship can be established as follows: $V_{GS\ (off)} < V_{th} < V_{GS\ (on)}$)

Be sure to take this into consideration when using the device.

Schottky Barrier Diode

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Forward voltage	$V_{F\ (1)}$	I_F = 0.1 A	—	0.31	0.36	V
	$V_{F\ (2)}$	I_F = 0.2 A	—	0.35	0.4	
	$V_{F\ (3)}$	I_F = 0.5 A	—	0.4	0.45	
	$V_{F\ (4)}$	I_F = 0.8 A	—	0.45	0.55	
Reverse current	I_R	V_R = 30 V	—	5.3	50	μA
Total capacitance	C_T	V_R = 0 V, f = 1 MHz	—	120	—	pF

Precaution

The Schottky barrier diode in this device has large reverse current leakage compared to typical switching diodes. Thus, excessive operating temperature or voltage may cause thermal runaway. To avoid this problem, be sure to take both forward and reverse loss into consideration.

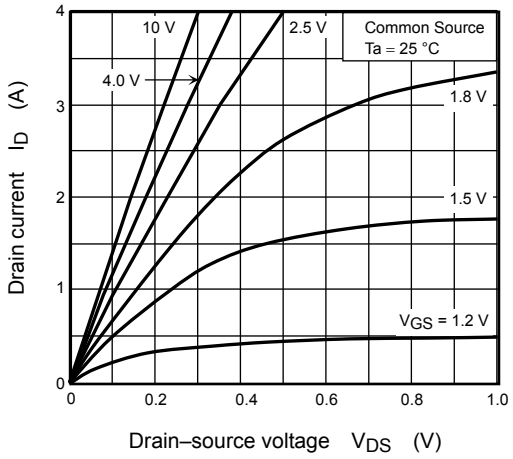
Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

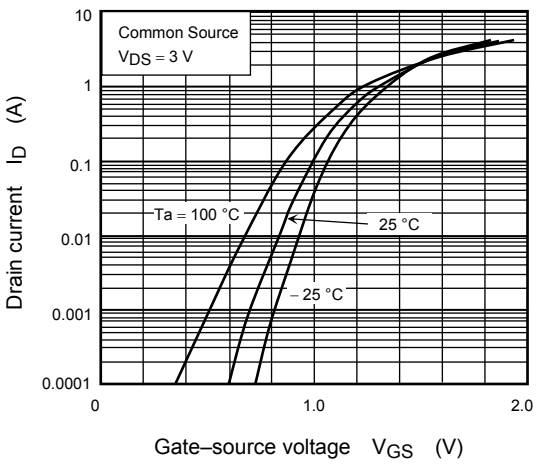
Thermal resistance $R_{th\ (j\text{-}a)}$ and drain power dissipation P_D vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration.

MOSFET

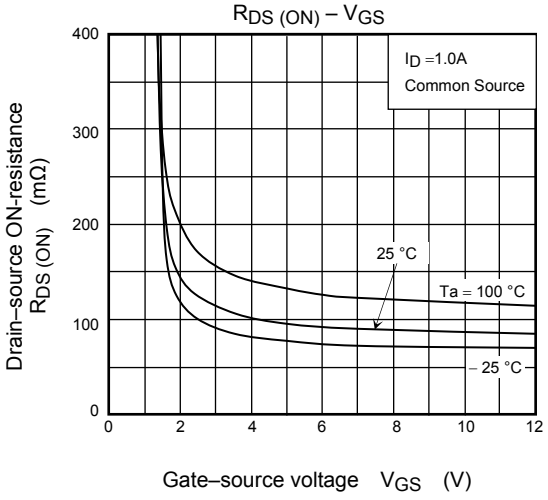
$I_D - V_{DS}$



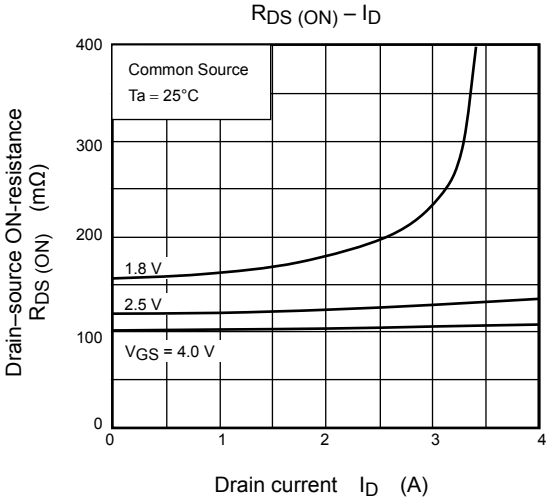
$I_D - V_{GS}$



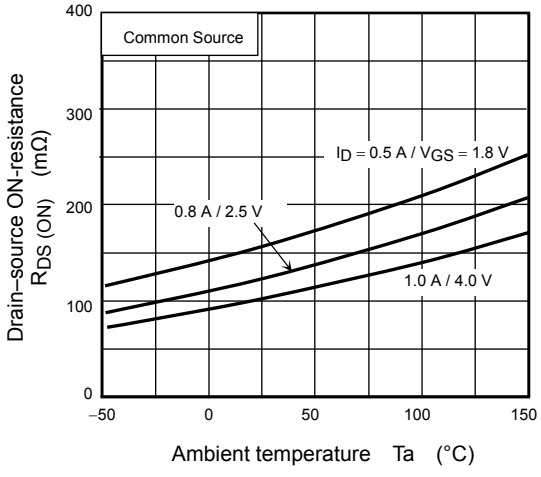
$R_{DS\ (ON)} - V_{GS}$



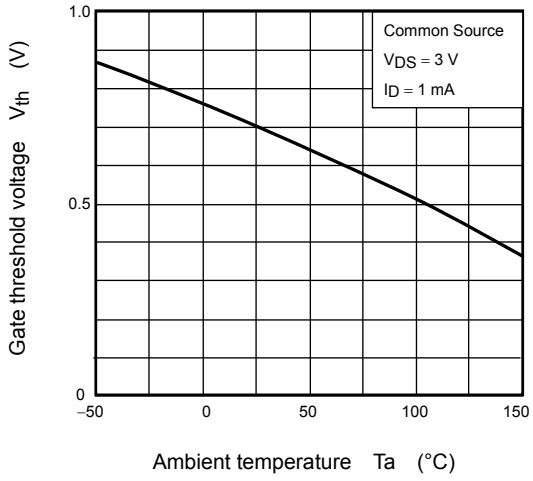
$R_{DS\ (ON)} - I_D$



$R_{DS\ (ON)} - Ta$

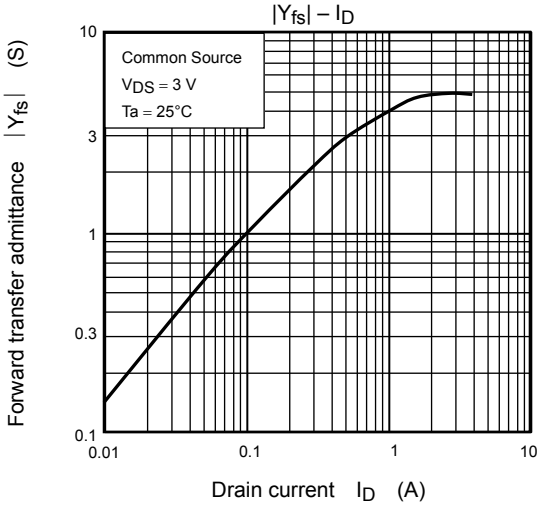


$V_{th} - Ta$

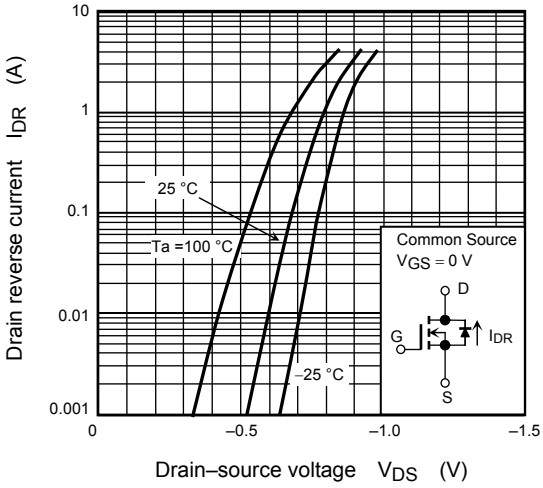


MOSFET

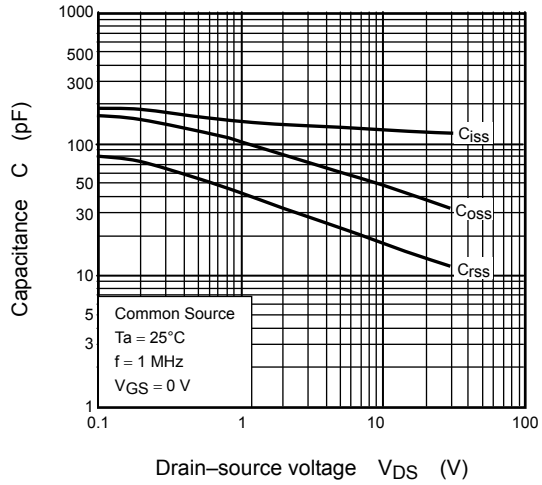
$|Y_{fs}| - I_D$



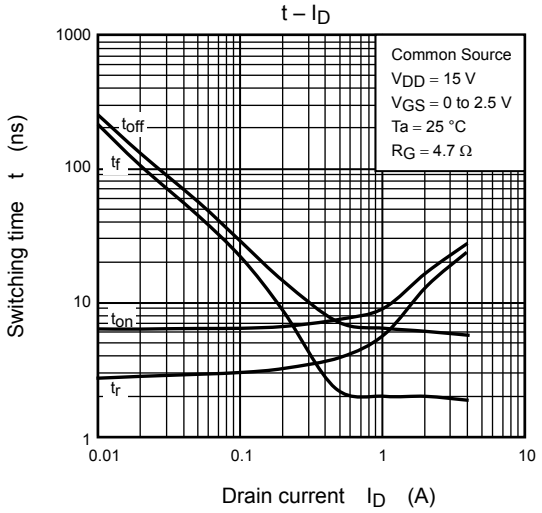
$I_{DR} - V_{DS}$



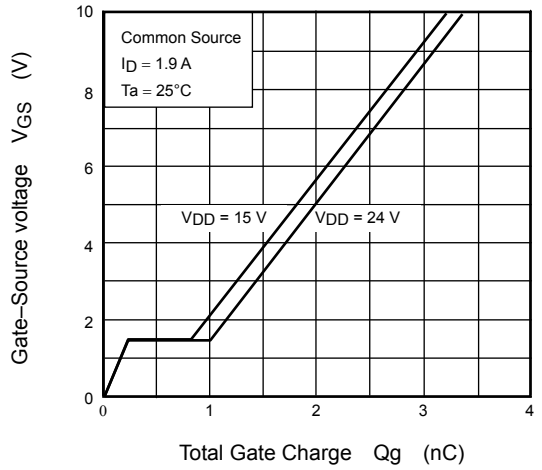
$C - V_{DS}$



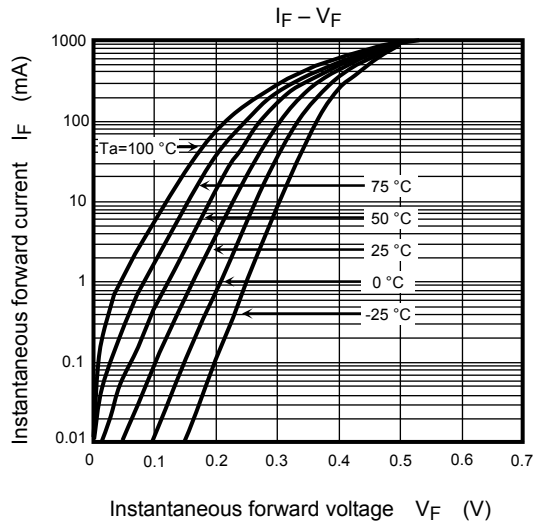
$t - I_D$

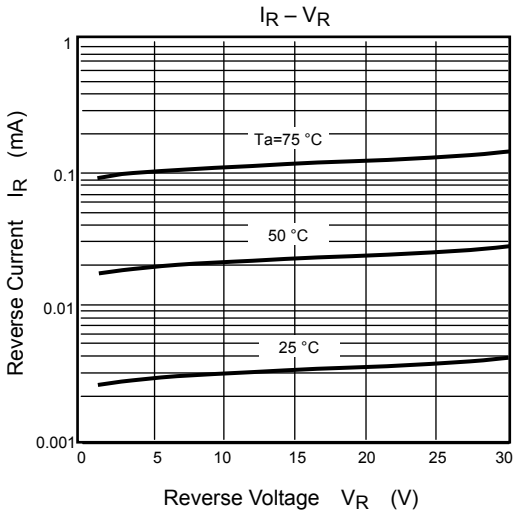


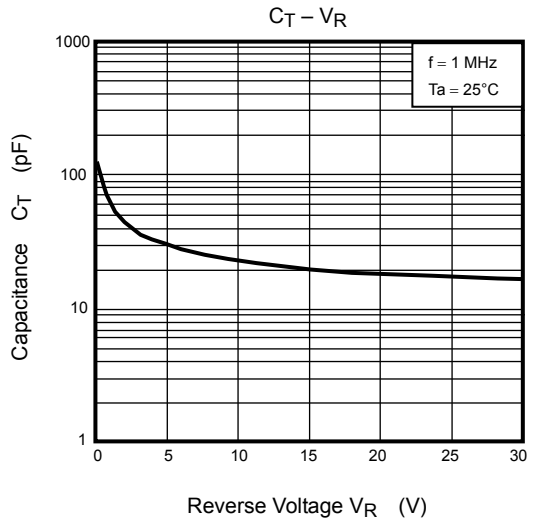
Dynamic Input Characteristic



Schottky Barrier Diode







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